Form Approved OMB No 0704-0188

AD-A242 589

ATION PAGE

16. RESTRICTIVE MARKINGS

. DISTRIBUTION / AV	AILABILITY OF REPORT
Approval for	public release
Distribution	list enclosed

4. PERFORMING ORGANIZATION REPORT NUMBER(S)

2b. DECLASSIFICATION / DOWNGRADING SCHEDULE

Technical Report No. 30

6a NAME OF PERFORMING ORGANIZATION State University of New York at Buffalo

6b OFFICE SYMBOL (If applicable)

5. MONITORING ORGANIZATION REPORT NUMBER(S)

Office of Naval Research

7b. ADDRESS (City, State, and ZIP Code)

7a. NAME OF MONITORING ORGANIZATION

6c. ADDRESS (City, State, and ZIP Code) Department of Chemistry

Buffalo, NY 14214

8a. NAME OF FUNDING / SPONSORING

Bb. OFFICE SYMBOL (If applicable)

Department of the Navy 800 North Quincy Street Arlington, VA 22217-5000

9 PROCUREMENT INSTRUMENT IDENTIFICATION NUMBER N00014-90-J-1530; R&T Code 4135002

Office of Naval Research 8c. ADDRESS (City, State, and ZIP Code)

Department of the Navy Arlington, VA 22217

10 SOURCE OF FUNDING NUMBERS

PROJECT NO

TASK NO

WORK UNIT ACCESSION NO 4135002

11. TITLE (Include Security Classification)

Organogallium Compounds Containing the Neophyl Substituent. The Crystal and Molecular Structure of $trans-[(PhMe_2CCH_2)_2GaN(H)(Pr)]_2$.

PROGRAM

ELEMENT NO

12. PERSONAL AUTHOR(S)

ORGANIZATION

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TO

13a. TYPE OF REPORT 36 TIME COVERED **FROM** Technical Report

14. DATE OF REPORT (Year, Month, Dav) 11 November 1991

15 PAGE COUNT 27

16 SUPPLEMENTARY NOTATION

To be published in Organometallics

17.	COSATI CODES		
FIELD	GROUP	SUB-GROUP	

18 SUBJECT TERMS (Continue on reverse if necessary and identify by block number) Gallium chemistry, organogallium compounds, galliumnitrogen compounds, x-ray structural study

19 ABSTRACT (Continue on reverse if necessary and identify by block number)

A series of organogallium compounds which contain the neophyl substituent including Ga(CH2CMe2Ph)3, Ga(CH2CMe2Ph)2Cl2 and (PhMe2CCH2)2GaN(H)(Pr) has been prepared in high yield by reactions typical or organogallium chemistry. The characterization data include elemental analyses, melting points, NMR and IR spectroscopic studies and cryoscopic molecular weight studies. All data are consistent with the conclusions that Ga(CH₂CMe₂Ph)₃ is monomeric in benzene solution whereas Ga(CH₂CMe₂Ph)₂Cl, Ga(CH₂CMe₂Ph)Cl₂ and (PhMe₂CCH₂)₂GaN(H)(Pr) are dimeric. The gallium amide [(PhMe₂CCH₂)₂GaN(H)(Pr)]₂ crystallizes in the centrosymmetric triclinic space group PI (No. 2) with a = 10.739(2), b = 10.844(2), c = 11.125(2)Å, $\alpha = 69.14(1)$, $\beta = 62.96(1)$, $\gamma = 76.74(1)$ °, $\overline{V} = 1074.7(3) \text{Å}^{3}$ and Z = 1. Diffraction data (MoK α , $2\theta = 5-\overline{5}0^{\circ}$) were collected on a Siemens R3m/V automated four-circle diffractometer and the structure was refined to R =3.57% and wR = 3.46% for all 3803 unique reflections (R = 2.52%, wR = 2.62% for those 3111 data with $|F_0| > 60(|F_0|)$). The molecule lies on a crystallographic inersion center and thus has a strictly planar Ga_2N_2 core. Distances of interest include $Ga-CH_2CMe_2Ph=1.992(3)$ Å and Ga-N(bridging)=2.013(2) and 2.029(2)Å.

20 DISTRIBUTION/AVAILABILITY OF ABSTRACT MUNCLASSIFIED/UNLIMITED ☐ SAME AS RPT

21. ABSTRACT SECURITY CLASSIFICATION Unclassified ☐ DTIC USERS

22a NAME OF RESPONSIBLE INDIVIDUAL O. T. Beachley, Jr.

22b TELEPHONE (Include Area Code) 22c OFFICE SYMBOL (716) 831-3266

DD Form 1473, JUN 86

Previous editions are obsolete

SECURITY CLASSIFICATION OF THIS PAGE

OFFICE OF NAVAL RESEARCH

Contract N-00014-90-J-1530

R&T Code 4135002

TECHNICAL REPORT NO. 30

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The Crystal and Molecular Structure of trans-[(PhMe_CCH_2)_GaN(H)(Pr)]_2

by

O. T. Beachley, Jr. *, M. J. Noble, Melvyn Rowen Churchill and Charles H. Lake

Prepared for Publication in Organometallics

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11 November 1991

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Organogallium Compounds Containing the Neophyl Substituent. The Crystal and Molecular Structure of trans-[(PhMe_CCH_2)_GaN(H)(Pr)]_2

by

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<u>Abstract</u>

A series of organogallium compounds which contain the neophyl substituent including $Ga(CH_2CMe_2Ph)_3$, $Ga(CH_2CMe_2Ph)_2C1$, $Ga(CH_2CMe_2Ph)C1_2$ and $(PhMe_2CCH_2)_2GaN(H)(Pr)$ has been prepared in high yield by reactions typical of organogallium chemistry. The characterization data include elemental analyses, melting points, NMR and IR spectroscopic studies and cryoscopic molecular weight studies. All data are consistent with the conclusions that $Ga(CH_2CMe_2Ph)_3$ is monomeric in benzene solution whereas $Ga(CH_2CMe_2Ph)_2C1$, $Ga(CH_2CMe_2Ph)C1_2$ and $(PhMe_2CCH_2)_2GaN(H)(Pr)$ are dimeric. The gallium amide $[(PhMe_2CCH_2)_2GaN(H)(Pr)]_2$ crystallizes in the centrosymmetric triclinic space group $P^{\frac{1}{2}}$ (No. 2) with $\underline{a} = 10.739(2)$, $\underline{b} = 10.844(2)$, $\underline{c} = 11.125(2)$ Å, $\underline{a} = 69.14(1)$, $\underline{B} = 62.96(1)$, $\underline{Y} = 76.74(1)^\circ$, V = 1074.7(3)Å and Z = 1. Diffraction data (Mo Ka, $Z\theta = 5-50^\circ$) were collected on a Siemens ZBm/V automated four-circle diffractometer and the structure was refined to ZBm/V automated four-circle diffractometer and the structure was refined to ZBm/V automated four-circle diffractometer and the structure was refined to ZBm/V

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for those 3111 data with $|F_0| > 6o(|F_0|)$. The molecule lies on a crystallographic inversion center and thus has a strictly planar Ga_2N_2 core. Distances of interest include $Ga-CH_2CMe_2Ph=1.992(2)$ and 1.994(3)Å and $Ga-N_2$ N(bridging) = 2.013(2) and 2.029(2)Å.

Introduction

The utilization of gallium in electronic materials including semiconductors and superconductors has led to a renewed interest in its chemistry. Even though a variety of organogallium compounds are known, relatively little is known about compounds which incorporate bulky organic substituents. Bulky substituents can lead to compounds with enhanced thermal stability as well as to compounds with unexpected structures. Consequently, our prior research involved investigations of the chemistry of gallium compounds with $\mathrm{CH_2SiMe_3}$, 1 $\mathrm{CH_2CMe_3}$, 2 2,4,6-Me₃-C₆H₂ 3 ,4 and $\mathrm{C_5Me_5}^5$,6 substituents but only the mesityl derivative $\mathrm{Ga(C_6Me_3H_2)Cl_2}$ displayed unusual chemistry. The compound $\mathrm{Ga(C_6Me_3H_2)Cl_2}$ was characterized as a unique one dimensional polymer in which planar $\mathrm{Ga(C_6Me_3H_2)Cl}$ units with distorted tetrahedral geometry were linked by bridging chloride ligands. The traditional structure of an organogallium dichloride is a chloride bridged dimer.

EXPERIMENTAL

All compounds described in this investigation were very sensitive to oxygen and moisture and were manipulated by standard vacuum line techniques or under a purified argon atmosphere. All solvents were purified before use. Gallium(III) chloride was purified by sublimation under dynamic high vacuum at 80-85 °C immediately prior to use. Neophyl chloride was purchased from Aldrich Chemical Co. and was distilled prior to use. Elemental

analyses were performed by Schwarzkopf Microanalytical Laboratory, Woodside, New York or by E+R Microanalytical Laboratories, Corona, New York. Infrared spectra of Nujol mulls or of the neat compound between CsI plates were recorded by means of a Perkin-Elmer 683 Spectrometer. Absorption intensities are reported with the abbreviations vs (very strong), s (strong), m (medium), w (weak), vw (very weak), sh (shoulder). The $^1\text{H NMR}$ spectra were recorded at 300 MHz or 90 MHz by using either a Varian Gemini 300 or Varian EM-390 spectrometer, respectively. All samples for NMR spectra were contained in sealed NMR tubes. Chemical shifts are reported in δ units (ppm) and are referenced to tetramethylsilane (TMS) as δ = 0.00 ppm and benzene as δ = 7.15 ppm. Melting points were observed in a Mel-Temp by using sealed capillaries. Molecular weights were measured cryoscopically in benzene by using an instrument similar to that described by Shriver and Drezdon. 7

Synthesis of Ga(CH₂CMe₂Ph)₃. In a typical experiment the Grignard reagent, (PhMe₂CCH₂)MgCl, was prepared from magnesium turnings (6.217 g, 255.8 mmol) and freshly distilled neophyl chloride (41.193 g, 244.22 mmol) in 100 mL of diethyl ether. The magnesium turnings were activated with iodine without stirring prior to addition of the neophyl chloride/ether solution. The reaction mixture was stirred under reflux for 18 h. A flask charged with 10.0 g (56.9 mmol) of GaCl₃ dissolved in 250 mL of dry diethyl ether was fitted with a condenser, mechanical stirrer, and a pressure equalizing addition funnel. Under a cover of argon the Grignard reagent solution was transferred to the addition funnel and was added to the GaCl₃ solution over a period of 30 minutes. After the addition was complete, the reaction mixture was stirred under reflux for 18 h. The Et₂O was then removed by vacuum distillation at room temperature. The crude product was

extracted from the ${\rm MgCl}_2$ by 4-5 washings with 150 mL of pentane to provide a yellowish "wet" solid which was purified by vacuum distillation in a short-path still at 120-210 °C. The first fraction which distilled at 120-150 °C was identified as bineophyl PhMe₂CCH₂CH₂CMe₂Ph by its 1 H NMR spectrum 8,9 and mp. 8,9 The second fraction which distilled at 160-210 °C was identified as pure ${\rm Ga(CH_2CMe_2Ph)_3}$ and was obtained as a colorless solid (19.8 g, 42.2 mmol, 74.1% yield based on ${\rm GaCl_3}$). More than one distillation was frequently required for complete removal of the bineophyl. The product isolated by distillation can be further purified, if needed, by recrystallization from pentane at -20 °C.

 $\frac{\text{Ga}(\text{CH}_2\text{CMe}_2\text{Ph})_3}{\text{Co.}} \quad \text{mp } 37.9-39.2 \text{ °C.} \quad ^{1}\text{H NMR } (\text{C}_6\text{D}_6, \delta): 7.08 \text{ (m, } 15\text{H, } -\text{C}_6\text{H}_5); 1.23 \text{ (s, } 18\text{H, } -\text{CMe}_2), 0.81 \text{ (s, } 6\text{H, } -\text{CH}_2-). IR (\text{Nujol mull, } \text{cm}^{-1}): 3110(\text{sh, m}), 3085(\text{s)}, 3059(\text{s)}, 3035(\text{s)}, 3021(\text{s)}, 1960(\text{sh, w}), 1941(\text{w}), 1885(\text{w}), 1869(\text{w}), 1800(\text{w}), 1742(\text{w}), 1668(\text{w}), 1598(\text{s}), 1579(\text{m}), 1535(\text{w}), 1490(\text{vs}), 1405(\text{m}), 1305(\text{w}), 1273(\text{m}), 1181(\text{s}), 1155(\text{m}), 1098(\text{m}), 1070(\text{s}), 1065(\text{sh, m}), 1028(\text{vs}), 998(\text{w}), 961(\text{w}), 925(\text{w}), 901(\text{m}), 858(\text{w}), 838(\text{w}), 761(\text{vs}), 725(\text{sh, s}), 698(\text{vs}), 660(\text{sh, m}), 620(\text{m}), 612(\text{m}), 551(\text{s}), 505(\text{w}), 457(\text{w}), 401(\text{w}), 269(\text{w}). Anal. calcd.: C, 76.77; H, 8.38. Found: C, 76.76; H, 8.56. Cryoscopic molecular weight, benzene solution, formula weight 469.36 (obsd. molality, obsd. mol. wt., association): 0.0846, 500.1, 1.07; 0.0536, 516.6, 1.10; 0.0372, 548.1, 1.17. Solubility: soluble in THF, Et_2O, benzene, and pentane. Trisneophylgallium(III) formed a stable 1:1 adduct with NMe_3, formed a weak 1:1 adduct with THF that slowly dissociated under dynamic vacuum, but did not form a stable adduct with Et_2O.$

Synthesis of $(PhMe_2CCH_2)_2GaCl$. In a typical experiment, $Ga(CH_2CMe_2Ph)_3$ (2.854 g, 6.081 mmol) and $GaCl_3$ (0.5353 g, 3.040 mmol) were weighed into

vials in the dry box. Both compounds were dissolved in pentane and then were pipetted into a 100 mL side arm flask. Each vial was rinsed several times (5-7) with fresh aliquots of pentane to ensure the quantitative transfer of reagents. After stirring the mixture at room temperature for 24 hours, the slightly cloudy solution was filtered through a medium glass frit. The product was then recrystallized from pentane at -10 °C to yield pure (PhMe₂CCH₂)₂GaCl as a colorless solid (3.135 g, 8.436 mmol, 92.5% yield).

 $\frac{\text{(PhMe}_2\text{CCH}_2)_2\text{GaCl}}{\text{Comp}}. \text{ mp } 86.4-87.8 °C. \quad ^{1}\text{H NMR} (C_6\text{D}_6, \delta): 7.15 (m, 10\text{H}, -C_6\text{H}_5); 1.35 (s, 4\text{H}, -\text{CH}_2-); 1.28 (s, 12\text{H}, -\text{CMe}_2). \text{ IR (Nujol mull, cm}^{-1}): 3082(s), 3055(s), 3019(vs), 2722(s), 1965(m), 1954(m), 1898(m), 1880(m), 1867(m), 1809(m), 1799(m), 1755(m), 1740(m), 1595(s), 1576(m), 1490(vs), 1398(sh, m), 1272(s), 1189(m), 1181(s), 1153(m), 1141(m), 1115(m), 1101(m), 1070(s), 1065(sh, m), 1025(s), 1001(m), 995(m), 948(m), 932(m), 928(m), 910(m), 901(m), 855(m), 835(sh, w), 768(sh, s), 761(s), 733(s), 719(s), 695(vs), 652(m), 612(w), 555(m), 512(w), 435(w), 420(w), 402(w), 315(vs), 280(w), 258(m), 242(sh, m). Anal. calcd.: C, 64.64; H, 7.05. Found: C, 64.35; H, 7.05. Cryoscopic molecular weight, benzene solution, formula weight 371.60 (obsd. molality, obsd. mol. wt., association): 0.0775, 773.2, 2.08; 0.0504, 769.4, 2.07; 0.0402, 769.1, 2.07. Solubility: soluble in THF, Et₂0, benzene, and pentane. Bisneophylgallium(III) chloride formed a stable 1:1 adduct with NMe₃ but did not form a stable adduct with Et₂0 or THF.$

Synthesis of $(PhMe_2CCH_2)GaCl_2$. Neophylgallium(III) dichloride, $(CH_2CMe_2Ph)GaCl_2$, was prepared by a stoichiometric redistribution reaction in the same manner as previously described for $(PhMe_2CCH_2)_2GaCl$. In a typical experiment $Ga(CH_2CMe_2Ph)_3$ (3.042 g, 6.480 mmol) and $GaCl_3$ (2.282 g,

12.96 mmol) were reacted in pentane to yield Ga(CH₂CMe₂Ph)Cl₂ (4.849 g, 17.71 mmol, 91.1%). The compound was purified by recrystallization from pentane at -30 °C.

 $\frac{\text{Ga}(\text{CH}_2\text{CMe}_2\text{Ph})\text{Cl}_2}{\text{Cl}_6\text{H}_5}, \quad 1.52 \text{ (s, 2H, -CH}_2\text{-), } 1.23 \text{ (s, 6H, -CMe}_2). \quad IR \text{ (Nujol mull, cm}^{-1}): \\ 3110(\text{w}), \quad 3090(\text{m}), \quad 3059(\text{vs}), \quad 3025(\text{vs}), \quad 2342(\text{vw}), \quad 2319(\text{w}), \quad 1965(\text{m}), \quad 1948(\text{m}), \\ 1890(\text{m}), \quad 1871(\text{m}), \quad 1820(\text{w}), \quad 1800(\text{m}), \quad 1778(\text{w}), \quad 1746(\text{m}), \quad 1680(\text{w}), \quad 1598(\text{s}), \\ 1579(\text{m}), \quad 1539(\text{m}), \quad 1509(\text{m}), \quad 1490(\text{vs}), \quad 1402(\text{sh, m}), \quad 1395(\text{s}), \quad 1309(\text{m}), \quad 1288(\text{sh, m}), \quad 1272(\text{s}), \quad 1240(\text{sh, m}), \quad 1205(\text{sh, m}), \quad 1190(\text{s}), \quad 1155(\text{m}), \quad 1131(\text{m}), \quad 1112(\text{m}), \\ 1102(\text{m}), \quad 1075(\text{m}), \quad 1062(\text{s}), \quad 1028(\text{s}), \quad 1005(\text{m}), \quad 995(\text{m}), \quad 980(\text{m}), \quad 960(\text{m}), \quad 945(\text{m}), \\ 931(\text{m}), \quad 905(\text{m}), \quad 862(\text{m}), \quad 835(\text{m}), \quad 767(\text{vs}), \quad 729(\text{vs}), \quad 705(\text{sh, s}), \quad 694(\text{vs}), \\ 639(\text{s}), \quad 554(\text{s}), \quad 509(\text{m}), \quad 440(\text{m}), \quad 415(\text{m}), \quad 380(\text{vs}), \quad 350(\text{s}), \quad 260(\text{vs}), \quad 230(\text{vs}). \\ \text{Anal. calcd.: C, } \quad 43.86; \quad 4, \quad 4.79. \quad \text{Found: C, } \quad 43.92; \quad \text{H, } \quad 4.96. \quad \text{Cryoscopic} \\ \text{molecular weight, benzene solution, formula weight } \quad 273.83 \text{ (obsd. molality, obsd. mol. } \text{wt., association): } \quad 0.0831, \quad 588.5, \quad 2.15; \quad 0.0574, \quad 569.7, \quad 2.08; \\ 0.0428, \quad 573.2, \quad 2.09. \quad \text{Solubility: soluble in THF, Et}_20, \quad \text{benzene, and} \\ \text{pentane. Neophylgallium(III) dichloride formed a stable 1:1 adduct with} \\ \text{NMe}_3 \text{ and THF but did not form a stable adduct with Et}_20. \\ \end{cases}$

Synthesis of $(PhMe_2CCH_2)_2GaN(H)(Pr)$. In a typical experiment, $Ga(CH_2CMe_2Ph)_3$ (2.16 g, 4.60 mmol) and propylamine (0.314 g, 5.31 mmol) were heated at 140-150 °C for 3d in a sealed tube. After heating, the volatile product from the elimination reaction $C_6H_5CMe_3$ and excess NH_2Pr were removed by vacuum distillation. The organogallium amide $(PhMe_2CCH_2)_2GaN(H)Pr$ was isolated by washing the product out of the reaction tube with pentane through a medium glass frit and was recrystallized at -30 °C to yield 1.514 g, 3.840 mmol, 83.4% yield based on $Ga(CH_2CMe_2Ph)_3$. Crystallographic

quality crystals were obtained by slow cooling of a saturated pentane solution to -30 °C.

<u>(PhMe₂CCH₂)₂GaN(H)(Pr)</u>. mp 129.3-131.0 °C. ¹H NMR (C₆D₆, δ): 7.37 (d, 4H, o-Ar, ${}^{3}J_{CCH} = 7.50 \text{ hz}$); 7.21 (t, 4H, m-Ar, ${}^{3}J_{CCH} = 7.50 \text{ hz}$); 7.06 (t, 2H, p-Ar, ${}^{3}J_{CCH} = 7.20 \text{ hz}$); 2.11 (q, 2H, -CH₂-, ${}^{3}J_{CCH} = 7.90 \text{ hz}$); 1.38 (s, 12H, $-CMe_2(neophyl)$); 0.92 (s, 4H, $-CH_2(neophyl)$ -); 0.87 (m, 2H, $-NCH_2-$); 0.66 (t, 3H, $-CH_3$, $^3J_{CCH} = 7.05 \text{ hz}$); 0.02 (t, 1H, -NH, $^3J_{CNH} = 7.65$ hz). IR (Nujol mull, cm^{-1}): 3298(s), 3082(s), 3050(s), 3019(vs), 2720(s), 1955(m), 1940(m), 1595(s), 1578(m), 1531(m), 1490(vs), 1439(sh, vs), 1361(vs), 1356(s), 1301(m), 1276(m), 1245(m), 1230(m), 1225(m), 1181(s), 1154(m), 1130(m), 1098(w), 1085(m), 1071(m), 1061(sh, m), 1052(vs), 1045(sh, m)s), 1025(s), 1010(s), 999(m), 989(sh, m), 979(m), 955(m), 926(w), 900(m), 889(m), 862(s), 845(s), 829(sh, m), 760(vs), 748(m), 715(vs), 695(vs), 686(s), 620(m), 599(m), 568(s), 550(m), 505(w), 499(m), 459(s), 439(sh, w), 409(sh, w), 399(m), 268(vw), 236(m). Anal. Calcd.: C, 70.07; H, 8.69. Found: C, 70.24; H, 8.75. Cryoscopic molecular weight, benzene solution, formula weight 394.25 (obsd. molality, obsd. mol. wt., association): 0.0833, 709, 1.80; 0.0663, 713, 1.81; 0.0508, 723, 1.83. Solubility: soluble in benzene and pentane.

Collection of X-Ray Diffraction Data for $[(PhMe_2CCH_2)_2Gan(H)(Pr)]_2$. The crystal selected for the structural study had well defined faces and approximate dimensions of $0.35mm \times 0.30mm \times 0.30mm$. Due to its extreme air sensitivity it was sealed into a thin walled capillary under strictly anaerobic conditions. The capillary was then mounted and aligned on a Siemens R3m/V four-circle single-crystal diffractometer. Details of data collection appear in Table 1.

The crystal belongs to the triclinic system, possible space groups being the centrosymmetric $P\overline{1}$ and the noncentrosymmetric P1. (The former was shown later to be the correct choice). An entire sphere of data (two equivalent forms) was collected for $2\theta = 5-50^{\circ}$ (Mo K α radiation). This was done to increase the quality of the crystal structure through the merging of the two forms of data. A total of 6274 reflections were collected and merged to 3803 unique data ($R_{int} = 1.8\%$). The resulting data were corrected for Lorentz and polarization effects. Absorption problems were corrected for by the use of a semi-empirical ψ -scan technique.

Solution and Refinement of the Structure of [(PhMe₂CCH₂)₂GaN(H)(Pr)]₂. The resulting data wet was fed into a VAX3100 workstation which was operating with the Siemens SHELXTL PLUS program system. Data reduction, structural solution and data refinement were performed under this system.

The resulting solution was in the centrosymmetric spacegroup P $\overline{1}$ (C_i^{-1} ; No. 2). The structure was solved by the use of direct methods followed by full matrix least-squares refinement. Positional and anisotropic thermal parameters for all non-hydrogen atoms and isotropic thermal parameters for the hydrogen atoms were refined as well as positional parameters for the unique N-bonded hydrogen atom of the u-NHPr ligand. All remaining hydrogen atoms were input in calculated positions with d(C-H) = 0.96Å. Following refinement, the largest features remaining on the electron density difference map were a maximum peak height of $0.30 \text{ e}^{-}/\text{Å}^3$ and a minimum of $-0.22 \text{ e}^{-}/\text{Å}^3$. This corresponded to a structural model which converged with reliability factors of R = 3.57% and wR = 3.16% for all 3803 unique data. (R = 2.52% and wR = 2.62% for those 3111 data with $|F_0| > 60(|F_0|)$.) The structure was also corrected for secondary extinction by refining the

parameter χ in the expression $F^* = F[1+0.002\chi F^2/\sin(w\theta)]^{-1/4}$; the refined value was $\chi = 0.0004(2)$.

Final atomic coordinates are collected in Table 2.

Lewis Acid-Base Studies. The tendency of $Ga(CH_2CMe_2Ph)_3$, $(PhMe_2CCH_2)_2GaCl_1$, and $(PhMe_2CCH_2)_2GaCl_2$ to form Lewis acid-base adducts with NMe3, Et20 and THF was investigated. In a typical experiment a weighed amount of excess Lewis base was vacuum distilled onto a weighed amount of the Lewis acid. After the resulting sample was warmed to room temperature and stirred for 1-2 hours, the excess base was removed by vacuum distillation. Mass measurements were used to determine the quantity of base which reacted. The mole ratio of Lewis acid to base which reacted, the melting point and the 1H NMR spectrum of the resulting adducts are described below. The Lewis acids $Ga(CH_2CMe_2Ph)_3$, $(PhMe_2CCH_2)_2GaCl$ and $(PhMe_2CCH_2)GaCl_2$ did not form stable adducts with Et20 or $(PhMe_2CCH_2)_2GaCl$ with THF.

 $\frac{(\text{PhMe}_2\text{CCH}_2)_3\text{Ga} \cdot \text{NMe}_3}{3}. \quad \text{Mol ratio Ga}(\text{CH}_2\text{CMe}_2\text{Ph})_3/\text{NMe}_3: \quad 0.99. \quad \text{mp } 119-134$ °C (dec.). $^1\text{H NMR}(\text{C}_6\text{H}_6, \delta): \quad 1.61 \text{ (s, 9H, NHe}_3), \quad 1.38 \text{ (s, 18H, -CMe}_2),$ 0.73 (s, 6H, -CH₂-).

 $\frac{(\text{PhMe}_2\text{CCH}_2)_2\text{C1Ga} \bullet \text{NMe}_3}{2^{1} \cdot 1.01 \cdot 1.00} . \quad \text{Mol ratio (PhMe}_2\text{CCH}_2)_2\text{GaC1/NMe}_3: \quad 1.01. \quad \text{mp}$ $76.5-80.1 \quad \text{°C.} \quad ^1\text{H NMR (C}_6\text{H}_6, \quad \delta): \quad 1.60 \quad (\text{s}, \quad 12\text{H}, \quad -\text{CMe}_2), \quad 1.52 \quad (\text{s}, \quad 9\text{H}, \quad \text{NMe}_3),$ $0.86 \quad (\text{s}, \quad 4\text{H}, \quad -\text{CH}_2\text{-}).$

 $\frac{(\text{PhMe}_2\text{CCH}_2)\text{Cl}_2\text{Ga} \bullet \text{NMe}_3}{2\text{Ga} \bullet \text{CCH}_2}. \quad \text{Mol ratio (PhMe}_2\text{CCH}_2)\text{GaCl}_2/\text{NMe}_3: \quad 0.92. \quad \text{mp}}{46.4-48.4 \, \circ \text{C}. \quad ^1\text{H NMR (C}_6\text{H}_6, \, \delta): \quad 1.67 \, (\text{s}, \, 15\text{H}, \, -\text{CMe}_2 \, \text{and NMe}_3), \, 1.57 \, (\text{s}, \, 2\text{H}, \, -\text{CH}_2-).}$

 $\frac{(\text{PhMe}_2\text{CCH}_2)_3\text{Ga} \cdot \text{THF}}{3}. \quad \text{Mol ratio Ga}(\text{CH}_2\text{CMe}_2\text{Ph})_3/\text{THF} \colon 0.96. \quad \text{mp } 98.7-102.6 \ ^{\circ}\text{C}. \quad ^{1}\text{H NMR} \ (\text{C}_6^{\,\text{H}}_6, \ \delta) \colon 3.40 \ (\text{m}, \ 4\text{H}, \ \text{THF}), \ 1.27 \ (\text{s}, \ 22\text{H}, \ -\text{CMe}_2 \ \text{and} \ \text{CMe}_2 \ \text{CMe}_2 \ \text{Mol ratio Ga}(\text{CH}_2\text{CMe}_2\text{Ph})_3/\text{THF} \colon 0.96. \quad \text{mp } 98.7-102.6 \ ^{\circ}\text{C}.$

THF), 0.80 (s, 6H, $-CH_2$ -). (PhMe₂CCH₂)₃Ga•THF was observed to very slowly dissociate at room temperature.

 $\frac{(\text{PhMe}_2\text{CCH}_2)\text{Cl}_2\text{Ga} \cdot \text{THF}}{2\text{Ga} \cdot \text{CH}_2}. \quad \text{Mol ratio } (\text{PhMe}_2\text{CCH}_2)\text{GaCl}_2/\text{THF} \colon 1.05. \quad \text{mp } 48.5-49.8 \quad \text{°C.} \quad ^1\text{H NMR } (\text{C}_6\text{H}_6, \delta) \colon 3.34 \quad (\text{m, 4H, THF}), 1.49 \quad (\text{s, 6H, -CMe}_2), 1.38 \quad (\text{s, 2H, -CH}_2-), 0.99 \quad (\text{m, 4H, THF}).$

RESULTS AND DISCUSSION

A series of organogallium compounds that incorporate the neophyl ligand including $Ga(CH_2CMe_2Ph)_3$, $Ga(CH_2CMe_2Ph)_2Cl$, $Ga(CH_2CMe_2Ph)Cl_2$ and $(PhMe_2CCH_2)_2GaN(H)(Pr)$ has been prepared by reactions typical of group 13 chemistry. The homoleptic derivative $Ga(CH_2CMe_2Ph)_3$ was prepared by a typical Grignard reaction in diethyl ether solution. The ether was readily removed as no apparent adduct formed. However, the isolation of pure samples of $Ga(CH_2CMe_2Ph)_3$ was hindered by contamination with bineophyl, $PhMe_2CCH_2CH_2CMe_2Ph$. Fractional distillation and recrystallization served to provide an analytically pure, colorless crystalline solid at room temperature. The halide derivatives were prepared from $Ga(CH_2CMe_2Ph)_3$ and $GaCl_3$ by using stoichiometric ligand redistribution reactions. The neophylgallium amide, $(PhMe_2CCH_2)_2GaN(H)(Pr)$ was prepared by an elimination reaction between $Ga(CH_2CMe_2Ph)_3$ and H_2NPr at 140-150 °C.

The characterization data for all compounds, which include partial elemental analyses (C, H), melting points, 1 H NMR and IR spectroscopic data, cryoscopic molecular weight studies and solubility properties, are consistent with the molecular formulas $Ga(CH_2CMe_2Ph)_3$, $[Ga(CH_2CMe_2Ph)_2Cl]_2$, and $[Ga(CH_2CMe_2Ph)Cl_2]_2$. It is noteworthy that all of the compounds have melting points which are higher than those for the corresponding neopentyl derivatives. 2 The structures of all three compounds would be expected to be

similar to most other organogallium compounds. The homoleptic derivative $Ga(CH_2CMe_2Ph)_3$ would be expected to be a trigonal planar molecule (GaC_3) whereas the chloride derivatives would be expected to have chloride bridges with four coordinate gallium atoms.

Lewis acid-base studies suggest that the neophylgallium compounds have Lewis acidities which are very similar to those of the corresponding neopentylgallium compounds.² If there is a difference, the neophyl derivatives might be slightly stronger Lewis acids. The replacement of a methyl group in the neopentyl group by a phenyl group might serve to reduce steric hindrance slightly and make the neophyl derivatives the stronger Lewis acids. Thus, Ga(CH2CMe2Ph), formed a 1:1 adduct with NMe2 and THF but the THF adduct appeared to slowly dissociate at room temperature. In contrast, trineopentylgallium did not form an adduct with THF and the characterization data for the $\ensuremath{\mathsf{NMe}}_{\ensuremath{\mathsf{Q}}}$ adduct suggested slight dissociation. The monochloride derivative Ga(CH2CMe2Ph)2Cl appears to be the weakest Lewis acid of the three derivatives studied as it was the only one of the three new gallium compounds which did not form an adduct with THF. However, an adduct was formed with NMe2. The chloride bridge bonds must compete effectively with the THF for the gallium acid site. The dichloride derivative, Ga(CH₂CMe₂Ph)Cl₂, formed 1:1 adducts with both THF and NMe₂.

Trineophylgallium(III) undergoes a facile elimination reaction at 140-150 °C with NH₂Pr to form (PhMe₂CCH₂)₂GaN(H)(Pr) and t-butylbenzene. The gallium-nitrogen product was fully characterized including an X-ray structural study. The unit cell contains one dimeric molecule which lies about a center of symmetry. All molecules are separated by normal van der Waal's distances and there are no anomalously short intermolecular contacts. Distances and angles are provided in Tables 3 and 4.

As shown in Figures 1 and 2, the dimeric molecule contains a Ga_2N_2 core which is required by symmetry to be planar. The n-propyl groups are arranged trans to each other across the ring. The Ga-N distances are: Ga(1)-N(1A) = Ga(1A)-N(1) = 2.013(2) Å and Ga(1)-N(1) = Ga(1A)-N(1A) =2.029(2)Å. These distances are slightly longer than the Ga-N distances observed for some other related gallium-nitrogen compounds (Table 5). The two gallium atoms are separated by 2.938(1)Å whereas the two nitrogen atoms are 2.776(3)Å apart. The internal ring angles are: N(1)-Ga(1)-N(1A) =86.7(1)° and Ga(1)-N(1)-Ga(1A) = 93.3(1)°. The CH_2CMe_2Ph ligands are bonded to gallium at distances of Ga(1)-C(20) = 1.992(2) Å and Ga(1)-C(30) = 1.992(2) Å1.994(3)Å, with an interligand angle of C(20)-Ga(1)-C(30) = 128.3(1)°. These ligands are displaced out of the Ga_2N_2 plane (as indicated by the Ga(1A) ••• Ga-C angles) by 61.0° and 67.6°, respectively. The Ga-C distances are slightly longer than the distances observed for the methyl groups bound to the gallium atoms that form the related Ga_2N_2 ring in [Me₂Ga]₂14aneN₄[GaMe₃] $_2^{15}$ of 1.933(7)Å but comparable to the average gallium-carbon distance in $[(Me_3CCH_2)_2GaPPh_2]_2^{16}$ of 2.003 \pm 0.009Å and in $[(t-Bu)_2GaP(C_5H_q)(H)]_2^{17}$ of 2.011(3)Å. The position of the unique hydrogen atom on nitrogen was refined, yielding an N-H distance of 0.817(30)Å and is comparable to the N-H distance in the closely related compound $[Cl_2GaN(H)(SiMe_3)]_2^{12}$ of 0.838(47)Å. The unique hydrogen in $[(PhMe_2CCH_2)_2GaN(H)(Pr)]_2$ is displaced from the gallium-nitrogen plane by 64.0° (defined by the angle N(1A)•••N(1)-H(1)). The α -carbon atom of the npropyl group is displaced from the Ga_2N_2 plane by 43.7° and is associated with the distance N(1)-C(41) = 1.483(3)Å. Angles around nitrogen are: $Ga(1)-N(1)-C(41) = 119.3(1)^{\circ}, Ga(1A)-N(1)-C(41) = 120.3(2)^{\circ}, Ga(1)-N(1)-H(1)$ = 102.5(15), Ga(1A)-N(1)-H(1) = 113.4(15)° and C(41)-N(1)-H(1) = 106.7(14)°.

Symmetry restraints require that the two amide hydrogens are trans to each other across the ring. All other distances and angles in the structure are normal.

The cryoscopic molecular weight studies of (PhMe2CCH2)2GaN(H)(Pr) identify the presence of dimeric molecules in benzene solution. The $^1\mathrm{H}\ \mathrm{NMR}$ spectrum of the compound further suggests the presence of only molecules in the trans conformation in solution as only one set of lines for CH_2 and CMe_2 protons for the neophyl ligand or for the propyl group protons was observed. If the cis isomer had been present, two sets of lines of equal intensity, one for each type of proton, would have been expected. Thus, the molecule in solution is the same as the molecule present in the crystalline solid. There was no change in either the degree of association or in the conformation of the molecule upon dissolution in benzene. In comparison, $[Me_2GaN(Me)(Ph)]_2^{18}$ existed as a mixture of cis (70%) and trans (30%) isomers in benzene solution. The sharp melting point of [Me_GaN(Me)(Ph)] (112-114 °C) and the presence of only one crystalline form was used to suggest only one isomer (probably trans) in the solid state. The related compound [Me₂InN(Me)(Ph)]₂¹⁸ existed as a trans isomer in the solid state according to a structural study whereas a mixture of cis and trans isomers were observed in solution. Thus, at least one metal nitrogen bond in these dimeric species was broken upon dissolution in order to have isomerization.

Acknowledgment. This work was supported in part by the Office of Naval Research and by a generous grant from Eastman Kodak Co. We thank the National Science Foundation for providing funds for the Siemens R3m/V diffractometer through a grant from the Chemical Instrumentation Program (89-13733).

Supplementary Material. Complete lists of distances and angles, anisotropic thermal parameters, calculated positions of hydrogen atoms and F_0/F_c list for $[(PhMe_2CCH_2)_2GaN(H)(Pr)]_2$ (pages). For ordering information, see any current masthead page.

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Table 1.

Experimental Data for the X-Ray Diffraction Study of trans- $\label{eq:cch2} \left[(\text{PhMe}_2\text{CCH}_2)_2\text{GaN}(\text{H})(\text{Pr}) \right]_2.$

Crystal Data

C46 H68 Ga2 N2
White
.35x.30x.30
Triclinic
ΡĪ
$\underline{a} = 10.739(2) \text{ Å}$
b = 10.844(2) Å
<u>c</u> = 11.125(2) Å
$\alpha = 69.140(10)^{\circ}$
$\beta = 62.960(10)^{\circ}$
$\gamma = 76.740(10)^{\circ}$
1074.7(3) Å ³
1
788.5
1.218 Mg/m ³
1.279 mm ⁻¹
420

Data Collection

Diffractometer Used Siemens R3m/V

Radiation $MoK\alpha (\lambda = 0.71073 \text{ Å})$

Temperature (K) 298

Monochromator Highly oriented graphite crystal

 2θ Range 5.0 to 50.0°

Scan Type $2\theta - \theta$

Scan Speed Constant; 1.00° /min. in ω

Scan Range (ω) 0.70° plus K α -separation

Background Measurement Stationary crystal and stationary

counter at beginning and end of scan, each for 25.0% of total

scan time

Index Ranges $-12 \le h \le 12, -12 \le k \le 12$

 $-13 \le \ell \le 13$

Reflections Collected 7606

Independent Reflections 3803 ($R_{int} = 1.93%$)

Observed Reflections 3803 (F > $0.3\sigma(F)$)

Observed Reflections 3111 (F > $6.0\sigma(f)$)

Absorption Correction Semi-empirical

Min./Max. Transmission 0.8180 / 0.9835

Solution and Refinement

System Used

Siemens SHELXTL PLUS (VMS)

Solution

Direct Methods

Refinement Method

Full-Matrix Least-Squares

Quantity Minimized

 $\sum w(F_0 - F_c)^2$

Absolute Structure

N/A

Extinction Correction

 $\chi = 0.0004(2)$, where

 $\mathbf{F}^* - \mathbf{F} [1 + 0.002\chi\mathbf{F}^2/\sin(2\theta)]^{-1/4}$

Hydrogen Atoms

Riding model, fixed isotropic U

Weighting Scheme

 $w^{-1} = \sigma^2(F) + 0.0005F^2$

Number of Parameters refined 264

Final R indices (0.25 σ data) R = 3.57 %, wR = 3.46 %

Final R indices (6.00 σ data) R= 2.52 %, wR = 2.62 %

R Indices (all data) R = 3.57 %, wR = 3.46 %

Goodness-of-Fit

0.97

Largest and Mean Δ/σ

0.002, 0.000

Data-to-Parameter Ratio 14.4:1

Largest Difference Peak 0.30 eÅ⁻³

Largest Difference Hole

-0.22 eÅ⁻³

Table 2. Final Atomic Coordinates ($\times 10^4$) and Equivalent Isotropic Displacement Coefficients ($\mathbb{A} \times 10^3$) for trans-[(PhMe₂CCH₂)₂GaN(H)(Pr)]₂.

	x .	у	z	U(eq)
Ga(1)	3757(1)	4258(1)	5639(1)	30(1)
N(1)	5819(2)	4025(2)	4368(2)	32(1)
H(1)	5794(23)	4060(21)	3633(23)	33(6)
C(20)	3404(2)	2824(2)	7450(2)	43(1)
C(21)	2207(3)	2956(2)	8868(2)	45(1)
C(22)	2117(3)	1598(2)	9989(2)	47(1)
C(23)	3115(3)	1106(3)	10522(3)	84(2)
C(24)	3076(4)	-123(4)	11489(4)	99(2)
C(25)	2049(4)	-907(3)	11932(3)	86(2)
C(26)	1034(4)	-451(3)	11444(3)	80(2)
C(27)	1068(3)	792(3)	10480(3)	63(1)
C(28)	2478(4)	3991(3)	9329(3)	76(2)
C(29)	819(3)	3416(3)	8687(3)	66(1)
C(30)	2733(2)	4745(2)	4402(2)	41(1)
C(31)	2441(2)	3672(2)	3966(2)	46(1)
C(32)	3808(3)	2933(2)	3200(2)	46(1)
C(33)	4793(3)	3586(3)	1917(3)	61(1)
C(34)	6015(4)	2928(4)	1196(3)	84(2)
C(35)	6291(4)	1608(4)	1733(5)	94(2)
C(36)	5347(5)	951(4)	3006(5)	101(3)
C(37)	4123(4)	1602(3)	3717(4)	75(2)
C(38)	1439(3)	2722(3)	5289(3)	64(1)
C(39)	1681(3)	4317(3)	2986(3)	70(2)
C(41)	6649(2)	2774(2)	4756(2)	41(1)
C(42)	8130(3)	2664(2)	3672(3)	50(1)
C(43)	8934(3)	1364(3)	4087(3)	72(2)

^{*} Equivalent isotropic U defined as one third of the trace of the orthogonalized \mathbf{U}_{ij} tensor

Ga(1)-N(1)	2.029(2)	Ga(1)-C(20)	1.992(2)
Ga(1)-N(1A)	2.013(2)	Ga(1)-C(30)	1.994(3)
Ga(1) • • • Ga(1A)	2.938(1)	N(1)-C(41)	1.483(3)
N(1) •••N(1A)	2.776(3)	N(1)-H(1)	0.817(30)

Table 4

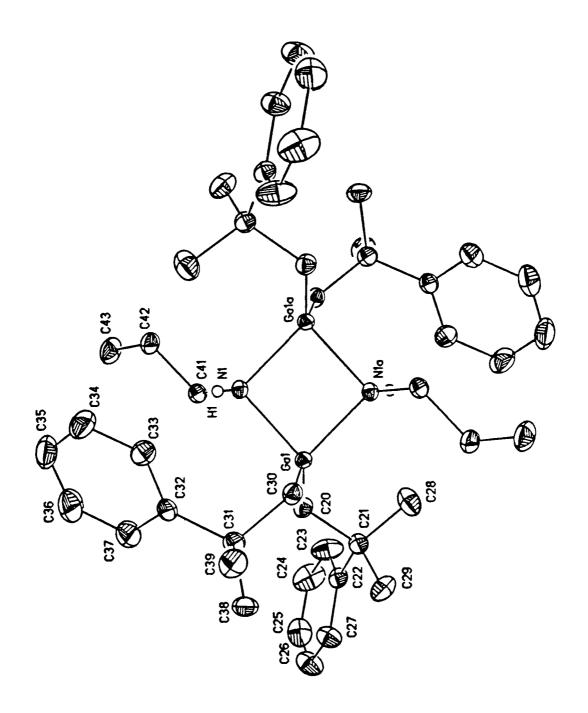
Important Interatomic Angles (°) for trans-[(PhMe₂CCH₂)₂GaN(H)(Pr)]₂.

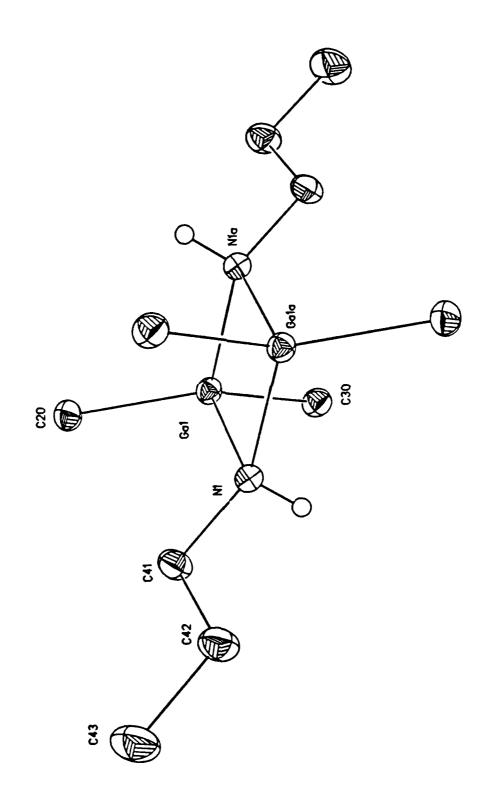
N(1)-Ga(1)-N(1A)	86.7(1)	C(20)-Ga(1)-C(30)	128.3(1)
N(1)-Ga(1)-C(20)	107.1(1)	N(1A)-Ga(1)-C(20)	114.3(1)
N(1)-Ga(1)-C(30)	105.9(1)	N(1A)-Ga(1)-C(30)	106.2(1)
Ga(1)-N(1)-Ga(1A)	93.3(1)	Ga(1)-N(1)-C(41)	119.3(1)
Ga(1)-N(1)-H(1)	102.5(15)	Ga(1A)-N(1)-C(41)	120.3(2)
Ga(1A)-N(1)-H(1)	113.4(15)	C(41)-N(1)-H(1)	106.4(14)

Compound	<u>Ga-N</u>	<u>Ga-C</u>	Reference
[Cl ₂ GaN(H)(SiMe ₃)] ₂	1.974(4)		12
2 3 2	1.964(4)		
[Cl ₂ GaN(Me)(SiMe ₃)] ₂	1.985(5)		12
2 3 2	1.983(5)		
	1.987(5)		
	1.989(5)		
$[H_2^{GaN(CH_2)}_2]_3$	1.97(2)		13
[H ₂ GaNH ₂] ₃	1.96(2)		14
3	1.96(2)		
	1.98(2)		
	1.96(1)		
$[Me_2Ga]_2[14]$ ane $N_4[GaMe_3]_2$	2.014(6)	1.933(7)	15
	2.003(6)		
[(PhMe ₂ CCH ₂) ₂ GaN(H)(Pr)] ₂	2.013(2)	1.992(2)	This work
	2.029(2)	1.994(3)	

Figure 1. The $[(PhMe_2CCH_2)GaN(H)(Pr)]_2$ molecule, with all C-bonded hydrogen atoms omitted.

Figure 2. The $[Ga(C)_2(\mu-NHC_3)]_2$ core of the molecule.





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